

N-Channel Enhancement Mode Field Effect Transistor

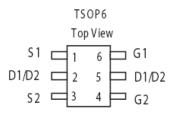
FEATURES

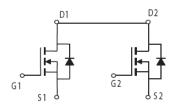
- Super high dense cell design for low RDS(ON)
- Rugged and reliable
- Simple drive requirement
- TSOP6 package

PRO	PRODUCT SUMMARY						
V	I_{DSS} I_{D} $R_{DS(ON)}$ $(m \Omega)$ Typ						
	20V	4A	21@ VGS=4.5V				
			35@ VGS=2.5V				



NOTE: The MT8205 is available in a lead-free package





ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	20	V
Gate-Source Voltage	V _{GS}	±12	V
Drain Current-Continuous ^a @Tj=125 ℃	ID	4	A
- Pulse d^{b}	Ідм	20	A
Drain-source Diode Forward Current ^a	Is	1.7	A
Maximum Power Dissipation ^a	PD	1.25	W
Operating Junction and Storage Temperature Range	TJ,Tstg	-55 to 150	$^{\circ}$ C

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to Ambient ^a	Rth JA	80	°C/W
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ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
OFF CHARACTERISTICS					•	
Drain-Source Breakdown Voltage	BVDSS	Vgs=0V,Id=250µA	20			V
Zero Gate Voltage Drain Current	Idss	VDS=16V,VGS=0V			1	μА
Gate-Body Leakage	Igss	V _G S=±8V,V _D S=0V			±100	nA
ON CHARACTERITICS						
Gate Threshold Voltage	V _G s(th)	$V_{DS}{=}V_{GS}, I_{D}{=}250\mu A$	0.5	0.8	1.5	V
Ducin Course On State Decistores	Dragov	Vgs=4.5V,Id=4A		21	25	- m Ω
Drain-Source On-State Resistance	Rds(on)	Vgs=2.5V,ID=2.8A		35	40	
Forward Transconductance	gFS	Vgs=5V,ID=5A		5		S
DAYNAMIC CHARACTERISTICS			•			
Input Capacitance	Ciss			608		pF
Output Capacitance	Coss	VGS=5V,ID=5A VDS=10V,VGS=0V f=1.0MHz		115		pF
Reverse Transfer Capacitance	Crss	1-1.011112		86		pF
SWITCHING CHARACTERISISTICS			•			
Turn-On Delay Time	tD(ON)	V _{DD} =10V		10		ns
Rise Time	tr	ID=6A,		14		ns
Turn-Off Delay Time	td(off)	V _{GEN} =4.5V R _L =10ohm R _{GEN} =10ohm		39		ns
Fall Time	tf			26		ns
Total Gate Charge	Q g			9.2		nC
Gate-Source Charge	Qgs	VDS=10V,ID=1A VGS=4.5V		1.6		nC
Gate-Drain Charge	Qgd	v U.S.—7.J v		2.6		nC

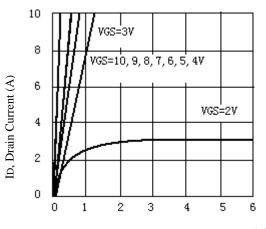


ELECTRICAL CHARACTERICS (TA=25°C unless otherwise noted)

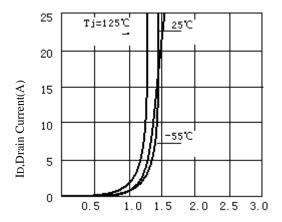
Parameter	Symbol	Condition	Min	Тур	Max	Unit	
DRAIN-SOURCE DIODE CHARACTERISTICS							
Diode Forward Voltage	Vsd	Vgs=0V,Is=1.7A		0.84	1.3	V	

Notes

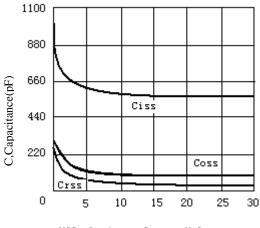
- a. Surface Mounted on FR4 Board, $t \le 10$ sec
- b. Pulse Test: Pulse Width ≤ 300Us, Duty Cycle ≤ 2%
- c. Guaranteed by design, not subject to production testing.



VDS, Drain-to-Source Voltage (V) Figure 1. Output Characteristics



VGS, Gate-to-source Voltage (V) Figure 2. Transfer Characteristics



VGS, Drain-to Source Voltage Figure3.Capacitance

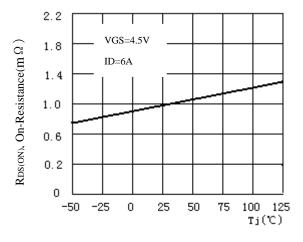
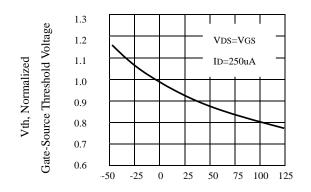
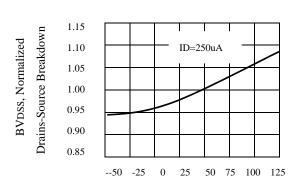


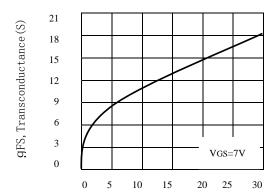
Figure 4. On-Resistance Variation with Temperature



 $\label{eq:total_continuity} Tj., Junction Temperature(^{\mathbb{C}})$ Figure 5. Gate Threshold Variation With Temperature



Tj, .Junction Temperature ($^{\circ}$ C)
Figure 6.Breakdown Voltage Variation
With Temperature



Ibs, Drain-Source Current (A)
Figure 7. Transconductance Variation

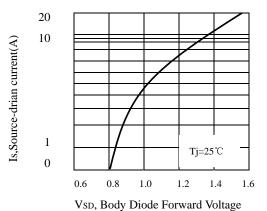


Figure 8. Body Diode Forward Voltage
Variation with Source Current

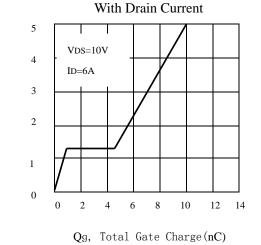
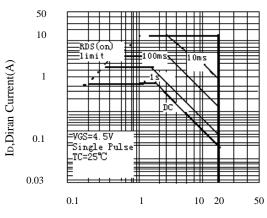


Figure 9. Gate Charge



VDS, Drain-Source Voltage(V)
Figure 10.Maximum Safe Operating Area

VGS, Gate to Source Voltage

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